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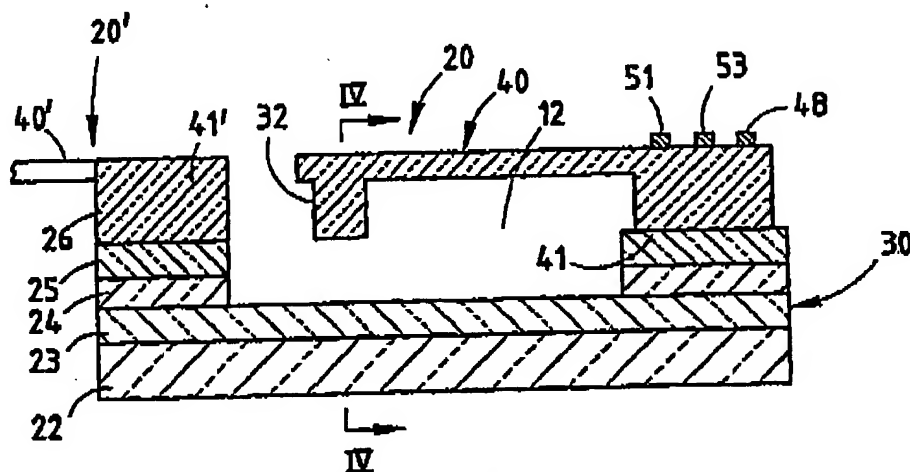
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(54) Title: MEMS OPTICAL SWITCH AND METHOD OF MANUFACTURE



(57) Abstract: An optical switch (20) on a planar optical circuit substrate (30) includes a cantilevered arm (40) having a control element (32) selectively movable into a waveguide slot (12) of the substrate for switching optical signals carried by the waveguide element (24). The arm (40) can be actuated by thermal or piezoelectric actuators to deflect between a rest position allowing a signal to continue along waveguide (24) and a second position with the control element (32) in slot (12) for blocking or changing direction of the signal. A second arm may be provided which moves laterally and is actuated in sequence with cantilevered arm (40) for overlying and latching cantilevered arm (40) in the second position, thus the switch can remain in an active state without further application of control signals. Arrays of MEMS switches formed on a single wafer by etching are bonded to arrays of waveguides to provide multiple switch modules.

**MEMS OPTICAL SWITCH AND METHOD OF MANUFACTURE  
BACKGROUND OF THE INVENTION**

1. Field of the Invention

5       The present invention relates to optical switches and particularly to MEMS switches.

2. Technical Background

10       Telecommunication systems utilizing optical waveguides require the use of optical switches for selectively coupling signal sources to one or more destinations. In planar optical components, MEMS switches have included a micro mirror positioned in a diagonal slot formed at the intersection of crossing planar waveguides having ports facing the slot. The micro mirror is moved laterally to reflect incoming light from one waveguide to an adjacent waveguide communicating with the slot to

15       perform a switching function. Such devices for a 16 x 16 input/output switch module requires an array of 256 MEMS switches. Although prior MEMS devices provide adequate switching functions, they are difficult to manufacture and their construction does not allow the formation of electrical circuits on the switch module for coupling electro-optical components to the combined MEMS and optical component.

20       There exists a need, therefore, for an improved MEMS optical switch and an optical switch module including MEMS switches in which an array of MEMS switches are joined with a planar optical circuit and which is capable of receiving electrical circuits for coupling electro-optical devices to the planar optical circuit. There also exists a need for a process for forming multiple switch arrays and multiple

planar optical circuit arrays which can be coupled for the mass production of optical switch modules.

#### SUMMARY OF THE INVENTION

5           The optical switch of the present invention satisfies this need by forming arrays of MEMS switches on a wafer substrate with each switch integrally including a cantilevered arm having a control element at one end for moving into a waveguide slot of planar optical circuit arrays to which the MEMS arrays are mounted. The control element moves in a direction orthogonal to the junction of the MEMS arrays and the optical circuit arrays and, in a preferred embodiment, comprises a mirror. 10           The cantilevered arm can be actuated by thermal, Piezoelectric, or electrostatic means to deflect the arm between rest and actuated positions. In the rest position, signal information from a waveguide port passes across the slot into a second waveguide port. When the switch is actuated, the mirrored end of the cantilevered arm extends 15           into the slot for selectively blocking or changing the direction of the incoming signal directing the signal to the port of a different waveguide.

          In an alternative embodiment of the invention, a second cantilevered arm is provided which moves in a plane orthogonally to the first cantilevered arm and is selectively actuated in sequence with the first cantilevered arm for overlying and 20           latching the first or switching arm in an actuated position, such that the MEMS switch can remain in an active state without further application of a control signal thereto. In all embodiments, the optical switch module so formed allows the formation of electrical conductors on a surface for the coupling of electro-optical components to the planar optical circuit, as well as for the actuation of the MEMS switches. This 25           invention also includes a method of simultaneously fabricating multiple optical switch modules utilizing masking, etching, depositing, and bonding steps to form such multiple optical switch modules, each with multiple arrays of fiber optical waveguides and arrays of MEMS switches as well as providing electrical circuits thereon.

          Additional features and advantages of the invention will be set forth in the 30           detailed description which follows and will be apparent to those skilled in the art from

the description or recognized by practicing the invention as described in the description which follows together with the claims and appended drawings.

It is to be understood that the foregoing description is exemplary of the invention only and is intended to provide an overview for the understanding of the nature and character of the invention as it is defined by the claims. The accompanying drawings are included to provide a further understanding of the invention and are incorporated and constitute part of this specification. The drawings illustrate various features and embodiments of the invention which, together with their description serve to explain the principals and operation of the invention.

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#### BRIEF DESCRIPTION OF THE DRAWINGS

Fig. 1 is a schematic view of a switching module which embodies a plurality of MEMS switches of the present invention;

Fig. 2 is an enlarged, fragmentary top plan view of one of the switching nodes shown in Fig. 1;

Fig. 3 is a vertical cross-sectional schematic view of a MEMS switch of a first embodiment of the present invention;

Fig. 4 is a cross-sectional view of the switch shown in Fig. 3, taken along section lines IV-IV;

Fig. 5 is an enlarged detailed view of the cantilevered arm construction shown in Fig. 3, showing the switching arm in a first at rest position;

Fig. 6 is a view of the switching arm shown in Fig. 5, shown actuated in a deflected second position;

Fig. 7 is a schematic, vertical cross-sectional view of an alternative embodiment of a cantilevered arm, shown in a first at rest position;

Fig. 8 is a view of the cantilevered arm shown in Fig. 7, shown in an actuated second position;

Fig. 9 is a top plan view of an alternative embodiment of a MEMS switch, including a latching arm;

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Fig. 10 is a cross-sectional view of the switch shown in Fig. 9, taken along section lines X-X;

Fig. 11 is a top plan view of switch shown in Figs. 9 and 10, shown in a latched position;

Fig. 12 is a cross-sectional view of the switch shown in Fig. 11, taken along section lines XII-XII;

Fig. 13 is a schematic view of an alternative latching member which can be employed with the MEMS switches of the present invention;

Fig. 14 is a schematic side elevational view illustrating a first step in the manufacturing of a MEMS switch according to the present invention;

Fig. 15 is a cross-sectional view of the structure shown in Fig. 14;

Fig. 16 is a schematic side elevational view illustrating a second step in the manufacturing of a MEMS switch according to the present invention;

Fig. 17 is a cross-sectional view of the structure shown in Fig. 16;

Fig. 18 is a schematic side elevational view illustrating a third step in the manufacturing of a MEMS switch according to the present invention;

Fig. 19 is a cross-sectional view of the structure shown in Fig. 18;

Fig. 20 is a schematic side elevational view illustrating a fourth step in the manufacturing of a MEMS switch according to the present invention;

Fig. 21 is a cross-sectional view of the structure shown in Fig. 20;

Fig. 22 is a schematic side elevational view illustrating a fifth step in the manufacturing of a MEMS switch according to the present invention;

Fig. 23 is a cross-sectional view of the structure shown in Fig. 22;

Fig. 24 is a schematic side elevational view illustrating a sixth step in the manufacturing of a MEMS switch according to the present invention;

Fig. 25 is a cross-sectional view of the structure shown in Fig. 24;

Fig. 26 is a schematic side elevational view illustrating a seventh step in the manufacturing of a MEMS switch according to the present invention;

Fig. 27 is a cross-sectional view of the structure shown in Fig. 28;

Fig. 28 is a schematic side elevational view illustrating a eighth step in the manufacturing of a MEMS switch according to the present invention;

Fig. 29 is a cross-sectional view of the structure shown in Fig. 28;

Fig. 30 is a schematic side elevational view illustrating a ninth step in the manufacturing of a MEMS switch according to the present invention; and

Fig. 31 is a cross-sectional view of the structure shown in Fig. 30.

#### DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENT

Fig. 1 is a schematic diagram showing an optical switch module 10 with an array of planar waveguides in the X/Y plane, such as waveguides A, B, C, and D, extending horizontally and crossing waveguides 1, 2, 3, and 4 extending vertically in the diagram. At each of the intersections of the waveguides there is formed a slot 12, as shown in the enlarged detail view of Fig. 2, which defines facing ports 15 and 17 of waveguide A and 11 and 13 of waveguide 3. Movably positioned within each slot of the switch module for movement in a vertical direction (i.e. in and out of the plane of Figs. 1 and 2) is a MEMS switch 20 embodying the present invention. Thus, each of the waveguide intersections, shown in the switch 10 of Fig. 1, will include a MEMS switch having a micro mirror which, when not actuated, permits optical input signals on, for example, waveguide A to pass from port 15 to port 17 to conduct signals along waveguide A from its input to its output. When a MEMS switch is actuated (such as switch 20 in Figs. 1 and 2), signals from the input of waveguide A at port 15 are reflected by the mirror of the MEMS switch onto port 13 of waveguide 3 to switch the signals from input A to output 3.

Alternatively, the MEMS switch, instead of including a micro mirror, may include an opaque material to selectively block the conducting of signals on a single waveguide providing an "on/off" function. Such construction is useful in a ring protection circuit where it is desired to stop the transmission of signals during a repair period along an optical pathway which has been damaged. More typically, a switching network, however, is provided such that multiple input lines can be selectively coupled to multiple output lines.

One embodiment of an optical switch module including MEMS switches 20 of the present invention is shown in Fig. 3, which shows an individual switch. It is to be understood, however, that a continuous array of such switches are simultaneously formed to align with an associated array of waveguides. In Fig. 3, a planar lightwave optical circuit 30 having a substrate 22 of silica is provided on which there is  
5 deposited in a conventional manner a doped silica under cladding 23, a doped silica waveguide 24 (Fig. 4) and a doped silica over cladding 25. Interrupting the waveguide 24 and, for example, orthogonally positioned waveguides, such as shown in Fig. 2, is a slot 12 which selectively allows a mirror 32 integrally formed at the  
10 end of a cantilevered arm 40 to selectively move between a position distal from slot 12, as shown in Figs. 3 and 4, to a position within the slot, as shown in phantom lines in Figs. 3 and 4 and in the optical pathway of the waveguides 24.

The fabrication of a MEMS switch forming one switch of an array and multiple arrays on a single wafer is shown in Figs. 14-31. The arrays of switches are  
15 formed on a  $\langle 110 \rangle$  single-crystal silicon wafer substrate, typically 100 mm in diameter, although other sized wafers may likewise be employed. An array of planar lightwave circuits 30, each associated with an array of MEMS switches, likewise are integrally formed on a silica wafer utilizing standard manufacturing techniques for forming a planar optical circuit including the flame hydrolysis deposition of the  
20 multiple layers and selective etching to form the switching slots 12.

The wafers, including the multiple arrays of MEMS switches and the multiple arrays of lightwave optical circuits are bonded using anodic bonding (with high fields such as 1 kV), fusion bonding at temperatures of approximately 1000° C or with an interfacial adhesive layer combining the array of MEMS switches to the array of  
25 optical circuits. The bonding precision between the silicon wafers forming the MEMS switches and the silica lightwave optical circuits is approximately  $\pm 2$  micrometers laterally and may be accomplished utilizing alignment marks on the wafers with commercially available equipment such as an SUSS ABS 150 bond cluster. Once bonded, the individual arrays are separated by dicing, using either a  
30 laser cutter or more commonly with a precision diamond saw. The number of optical

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modules defined by a bonded lightwave optical circuit array and associated MEMS switch array naturally depends upon the size of each array but, for example, 21 4 x 4 arrays can be obtained from a 100 mm diameter wafer. Only four 32 x 32 switch modules will be available on a single wafer as the area consumed progresses geometrically.

The formation of the planar lightwave circuit is by conventional processes to yield the array of planar lightwave circuits to which the MEMS switches can be attached. The formation of the MEMS switches, however, is unique and is now described in connection with Figs. 14-31, yielding the various geometries shown in Figs. 5-13.

Initially, as shown in Figs. 14 and 15, a  $\langle 110 \rangle$  single-crystal silicon wafer substrate having a thickness of about 20 microns in wafer form with a diameter of approximately 100 mm in one embodiment is provided. The lower surface, as seen in Figs. 16 and 17, is masked with a mask of silicon nitride ( $\text{Si}_3\text{N}_4$ ) to allow the subsequent etching using photolithography to form the desired matrix pattern defining an array of individual switches. Other masking materials can likewise be employed as long as they are capable of withstanding the crystal lithographic etching solution described with respect to subsequent processing steps.

Next, as indicated by Figs. 18 and 19, the  $\text{Si}_3\text{N}_4$  is exposed utilizing photolithography and reactive ion etching to form the initial geometry of the MEMS switches which results in defining the arm 40 and mirrored end 30 of each of the switches. Thus, the tip of end 32 underlying the  $\text{Si}_3\text{N}_4$  pad 213 (shown in Fig. 18) will subsequently become the control element for each MEMS switch. The areas of the lower surface 201 of the silicon wafer 200 are next etched utilizing an approximately 4 molar potassium hydroxide (KOH) solution and next the  $\text{Si}_3\text{N}_4$  washed away, resulting in the structure shown in Figs. 20 and 21 in which the arm 40 is partially formed, as is the control element 32. Other crystal lithographic etching solutions, such as ethylene diamine pyrocatechol or TMAH (tetramethyl ammonium hydroxide) may be used in place of KOH. It is important that the crystal lithographic etching solution, however, provide a high quality silicon mirror having a smooth



surface capable of receiving a reflective layer, such as gold, which is deposited, as indicated by Figs. 22 and 23, by thermal evaporation to a thickness of 40 nm on the opposite sides 31, 33 of the control element 32.

5 Next, the arrays of partially completed MEMS switches 20 are bonded to the planar optical circuit 30 as noted earlier by the anodic, fusion, or interfacial adhesive bonding. This results in the partially completed optical circuit as illustrated in Figs. 24 and 25. The upper surface 203 of the silicon wafer can then be polished as desired or necessary so that the electrical circuits as shown in Figs. 28 and 29 can be deposited thereon.

10 Next, a layer of insulator material 44 is deposited on the upper surface 43 of arm 40. The insulator can be any suitable material allowing the flexing of the arms, such as silica ( $\text{SiO}_2$ ). Finally, a layer of conductive material 46, which heats upon the application of an electrical current thereto, is deposited over the insulating strip 40 forming an L-shaped conductive member which, when a control signal is applied  
15 between element 46 and the base 42 of arm 40, as seen in Fig. 6, the arm will deflect downwardly due to the larger thermal expansion of the member 46 as compared to the silicon base 42. The heating strip defined by the conductive layer 46 has a depth of approximately 2 microns and a conductive pad 49 is deposited on the base 42, as seen in Figs. 6 and 29, to allow a control voltage to be applied between the conductive  
20 layer 46 and base 42, thereby heating the arm, causing its deflection to an actuated position. At this point of the construction and simultaneously with the depositing of contact 49, electrical conductors 48, and contact pads 51, 53 (Figs. 3 and 4) for the attachment of electro-optical devices to the upper surface 43 of the MEMS switch matrices can be added such that electro-optical components can be integrally mounted  
25 to the switch matrix 10. Conductors 48 typically will be gold formed through a suitable mask to provide a pattern of conductors required for a given circuit construction. At this time in the manufacturing process, the cantilevered arm 40 is not yet free to move and reactive ion etching is applied to either side of the arm 40, as best seen in Fig. 31, to remove the bridge material and free the arm from the  
30 lateral supports between base 41 and arm 40.

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Each MEMS switch of the array forming an optical switch module integrally includes a second base 41' with a second array of MEMS switches 20' with arms 40', as seen in Fig. 3. The control of the MEMS switches so formed is provided by a power source illustrated at 50 in Fig. 6, which represents a switched electrical control for applying current to heating elements 46 for selectively heating arms 40 which will subsequently bend downwardly, in a direction indicated by arrow C in Fig. 6, a distance of approximately 20 microns sufficient to block or reflect signals in waveguides 24 for either blocking a signal or switching a signal as illustrated in the network of Fig. 1.

Gap 12 typically will have the smallest width possible, such as 6 microns or less, while the width of control element 32 of cantilevered arm 40 is approximately one-third that of the gap to provide sufficient clearance for the movement of the MEMS switch element into and out of the optical pathway across gap 12. Arm 40 is thin enough to allow flexing through thermal heating as illustrated in Fig. 6 and yet thick enough to be sufficiently rigid to maintain its at rest or off position, as shown in solid lines in Figs. 3-5.

The amount of current necessary to activate an arm having a thickness of approximately 20 microns, a length of approximately 350  $\mu$  and a width of approximately 50  $\mu$  was less than 10 milliamperes with an applied voltage of about 10 volts. The voltage and resultant current can be varied as desired for the given dimensions of the arm, however, only a relatively low voltage and current are necessary. The base 200 (Fig. 14) for forming the array of MEMS switches 20 on the planar optical circuit 10 may include numerous other electrical conductors, such as 51 and 53 illustrated in Fig. 3. for coupling to other electro-optical devices, such as photo diodes, solid state lasers, and the like, which may be employed with a planar optical circuit 30 on which the MEMS switch array is integrally formed. Thus, the area of upper surface 47 of the MEMS switches not occupied by the switching arrays provides an integral platform for the deposition of electrical conductors and for the mounting of electro-optical components thereto.

The cantilevered arm construction of the MEMS switches 20 allows the thermal actuation by utilizing an electrically actuated thermal strip 46 to cause the deflection of the arm as illustrated in Figs. 5 and 6 for selectively switching signals in an optical network, such as shown in Fig. 1, by moving in a vertical direction, thereby freeing the space above the cantilevered arm at its base for the mounting of electro-optical components thereon. In place of the thermally actuated cantilevered arm, other actuating arms can be employed, such as shown in the schematic diagrams of Figs. 7 and 8, now described.

In Fig. 7, a MEMS switch employing a cantilevered arm 60 is fabricated to include a reflective control element 61 in the same process as in the first embodiment. The array of switches are also bonded to an optical circuit (not shown) of the same construction and formed in substantially the same manner as the embodiment shown in Figs. 3-6. In place of a layer of insulating material and a thermal-actuating element, however, a layer of Piezoelectric material 62 is deposited on the upper surface 63 of the arms body 64 to a thickness of about 4 microns. The Piezoelectric material can be, for example, PZT. An over-layer 66 of a metallic conductor having a thickness of about 2 microns covers the Piezoelectric layer 62. Thus, the Piezoelectric layer 62 is positioned between an upper conductive layer 66 and silicon base 64.

In the embodiment shown in Figs. 7 and 8, conductive pads 71 and 73 are formed on the surfaces of conductors 66 and base 64, such that an actuating control signal represented by voltage source 70 can be applied to the cantilevered arm 60 causing its deflection as illustrated in Fig. 8. The arm 60 has substantially the same dimensions as control arm 40 shown in the previous embodiment. A 10 volt control signal provides a deflection of 20 micrometers, resulting in movement of the arm between an at rest position, illustrated in Fig. 7, to an actuated position, illustrated in Fig. 8.

In some applications, it is desired to have an optical switch, such as MEMS switches 20, maintained in an actuated state for extended period of time, such as when used as a protection device in a ring circuit during repairs of an optical

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communication network. In this and other instances (the switch normally can be actuated at a rate of, for example, 20 milliseconds), it would be necessary to apply a continuous voltage on the embodiment shown in Figs. 7 and 8 or a continuous current as shown in the embodiments of Figs. 3-6. In order to avoid the necessity of such continuous application of a control signal, a latching structure, shown in Figs. 9-12, can be provided to selectively latch the MEMS switch in a downwardly light-blocking or reflecting position in the substrate slot 12. For purposes of illustrating this aspect of the invention, the planar optical waveguide structure supporting the switch and latching arms illustrated in these figures is not shown in detail.

Referring now to Figs. 9-12, there is shown a pair of latching MEMS switch assemblies 75, each of which include a cantilevered switching arm 80 which can be of the construction shown in Figs. 3-6 or 7 and 8 and which includes a mirror 82 extending in a plane orthogonal to arm 80. Thus, arm 80 moves upwardly and downwardly or vertically with respect to the planar lightwave circuit in a direction indicated by arrow D in Fig. 10, while latching arm 90 moves laterally or horizontally in a direction indicated by arrow E in Figs. 10 and 12. Arm 90 is of substantially the same construction as the actuator arm shown in Figs. 3-8 except it is formed to move in a plane orthogonal to the movement of arm 80 and responds to control signals to operate in sequence with switch arm 80 to latch the switch arm into an "on" or activated position as now described.

As before, an electrical current or voltage is applied to the arm 80 depending upon its construction to cause it to move downwardly into an actuated position, as seen in Fig. 12, for blocking or reflecting light through the planar optical waveguide. While actuated and in its lowered position as shown in Figs. 11 and 12, latching arm 90 is also activated by the application of a current or voltage thereto, causing it to move laterally in a direction indicated by arrow E over and engaging the top surface 81 of switch arm 80 with the lower surface 91 of arm 90 frictionally engaging the top surface 81 of arm 80. While a control signal is applied to latching arm 90, the control signal is removed from arm 80 such that it tends to move upwardly but is blocked from moving from the actuated position by its engagement with arm 90. The

control signal to arm 90 can then be removed and the frictional engagement at the interface 85 between arms 80 and arms 90 prevents the further movement of either of the arms, thereby latching switch 75 so formed in an actuated state. When it is  
5 desired to move the light blocking or reflecting member 82 from the slot 12 in the optical waveguide circuit, the actuating signal is again applied to arm 80, causing it to deflect downwardly slightly thereby removing the frictional engagement at 85 and allowing arm 90 to return to its at rest, undeflected position shown in Figs. 9 and 10. The control signal is then removed from arm 80, and it returns to its undeflected  
10 "off" position.

Yet another embodiment of the latching switch is shown in Fig. 13 as 75' in which an actuating switching arm 80 is provided and a latching arm 100 is positioned to move laterally adjacent and over the upper surface 81 of arm 80. Arm 100 is an electro-statically movable arm comprising a vertically extending silicon substrate 102  
15 having a plurality of spaced conductive plates 104 extending outwardly therefrom for receiving alternately staggered conductive plates 106 formed on an insulative substrate of silicon 108 coupled to the side wall 109 of a planar lightwave circuit substrate by means of a collapsible mounting structure 110 such as a bellows. The application of an electrical control signal through a power supply 112 (shown  
20 schematically in Fig. 13) to conductive surfaces 113 and 114 electrically coupled to plates 104 and 106, respectively, causes an electro-static attraction which moves the latch pin in a direction indicated by arrow F in Fig. 13 to selectively overly switch actuator arm 80. The sequence of operation is identical to that of the embodiment shown in Figs. 9-12 with the switch arm 80 first being actuated then the latching arm  
25 100 next being actuated, while the switch arm signal is then removed to cause a frictional engagement between the lower surface of arm 100 and the upper surface 81 of arm 80, at which time the control signal from source 112 can be disconnected from the actuator arm 100 and the optical switch remains in an activated position.

Thus, with the MEMS switching system of the present invention, multiple  
30 switch modules can be fabricated with each module including an array of MEMS switches and planar optical circuits to allow network switching of signals from one

series of waveguides to another series of waveguides, provide on/off switching and other optical switching functions by providing an integrally formed optical circuit and MEMS switches which also accommodate electrical conductors for the mounting of  
5 electro-optical components to the optical circuit of the modules. Additionally, the present invention provides a latching arm, such that the MEMS switches can be latched in an actuated position without the continuous application of a control signal thereto.

It will become apparent to those skilled in the art that various modifications to  
10 the preferred embodiments of the invention as described herein can be made without departing from the spirit or scope of the invention as defined by the appended claims.

The invention claimed is:

1. An optical switch comprising:

a substrate including an optical waveguide, wherein the waveguide includes spaced-apart ports;

5 an arm mounted in a cantilevered manner to the substrate;

an actuator for deflecting said arm in a plane orthogonal to the plane of the substrate; and

10 a control element mounted to said arm, whereby actuation of the arm moves the control element between the ports to control transmission of optical energy in the waveguide.

2. The optical switch of claim 1 wherein the substrate defines a planar optical circuit integrally including at least one waveguide.

15 3. The optical switch of claim 2 wherein the optical circuit includes a slot formed therein to define the ports of the waveguide.

4. The optical switch of claim 3 wherein the control element of the cantilevered arm selectively extends into the slot.

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5. The optical switch of claim 4 wherein the control element is a mirror.

6. The optical switch of claim 1 wherein the actuator is a thermal actuator.

25 7. The optical switch of claim 6 wherein the arm is fabricated of a silicon material and the thermal actuator includes a thin conductive film.

8. The optical switch of claim 1 wherein the actuator comprises a Piezo-electric element coupled to the arm to deflect said arm.

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9. The optical switch of claim 1 and further including a latch arm mounted to the substrate and is selectively coupled to the arm to hold the arm in an actuated position.

5 10. The optical switch of claim 9 wherein the latch arm includes an actuator for moving the latch arm in a direction orthogonal to the arm for overlying the arm when the arm and latch arm are actuated.

10 11. The optical switch of claim 10 wherein the actuator for the latch arm is a thermal actuator.

12. The optical switch of claim 10 wherein the actuator for the latch arm is a Piezoelectric actuator.

15 13. The optical switch of claim 10 wherein the actuator for the latch arm is an electrostatic actuator.

14. An optical switch module comprising:  
an array of orthogonally extending optical waveguides formed in a planar substrate with a diagonal slot formed at the intersection of the waveguides to define input and output ports;

20 an array of MEMS switches mounted to the planar substrate, wherein each MEMS switch includes an arm mounted in cantilevered fashion to the substrate for movement to selectively extend into a slot to switch the optical energy in one waveguide of the substrate to another waveguide of the substrate; and electrical  
25 conductors deposited on a surface of said array of MEMS switches opposite said substrate.

15. The optical switch module of claim 14 wherein said array of MEMS switches are integrally formed in a single-crystal silicon wafer.

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16. A method of manufacturing an array of MEMS switches comprising the steps of:

providing a single-crystal silicon wafer substrate;

coating a surface of the substrate with a photolithographic film;

5 exposing an etching pattern on the film with a photolithographic light source;

reactive ion etching the film;

applying a crystallographic etching solution to the exposed wafer substrate to define a plurality of arms, control elements, and bases integrally coupled to one another; and

10 etching the silicon wafer adjacent each of the control elements to define cantilevered arms, each with the control element extending from one end thereof.

17. The method of claim 16 and further including depositing a reflective film on opposite sides of each of the control elements.

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18. The method of claim 17 wherein said depositing step comprises depositing gold on the sides of the control element.

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19. The method of claim 17 and further including applying an actuator on each of the cantilevered arms.

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20. The method of claim 19 wherein the applying step comprises depositing an insulating strip on each of the arms and depositing a thermally conductive element over each of the insulating strips.

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21. The method of claim 19 wherein the applying step comprises applying a Piezoelectric material to each of the arms and a conductive material over the Piezoelectric material.

22. The method of claim 16 and further including bonding the silicon wafer in alignment to an optical circuit array.

23. A latching optical switch comprising:

5 a substrate including an optical waveguide, wherein the waveguide includes spaced-apart ports;

a switching arm mounted in a cantilevered manner to the substrate and including an actuator for deflecting said arm in a plane orthogonal to the plane of the substrate, such that a control element mounted to said arm moves between the ports to control the transmission of optical energy in the waveguide; and

10 a latch arm mounted to the substrate and including an actuator to selectively move the latch arm over the switching arm to hold the switching arm in an actuated position.

15 24. An optical switch module comprising:

an array of orthogonally extending optical waveguides formed in a planar substrate with a diagonal slot formed at the intersection of the waveguides to define input and output ports;

20 an array of MEMS switches mounted to the planar substrate, wherein each MEMS switch includes an arm mounted in cantilevered fashion to the substrate; an actuator for deflecting the arms in a plane orthogonal to the substrate; and a control element mounted to the arm, whereby the arm and control element are positioned on the substrate to selectively extend into a slot to switch the optical energy in one waveguide of the substrate to another waveguide of the substrate.

25 25. The optical switch of claim 24 wherein the control element is a mirror.

26. The optical switch of claim 24 wherein the actuator is a thermal actuator.

27. The optical switch of claim 26 wherein the arm is fabricated of a silicon material and the thermal actuator includes a thin conductive film.

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28. The optical switch of claim 24 wherein the actuator comprises a Piezoelectric element coupled to the arm to deflect said arm.

5 29. The optical switch of claim 24 and further including a latch arm mounted to the substrate and is selectively coupled to the arm to hold the arm in an actuated position.

10 30. The optical switch of claim 29 wherein the latch arm includes an actuator for moving the latch arm in a direction orthogonal to the arm for overlying the arm when the arm and latch arm are actuated.

31. The optical switch of claim 30 wherein the actuator for the latch arm is a thermal actuator.

15 32. The optical switch of claim 30 wherein the actuator for the latch arm is a Piezoelectric actuator.

20 33. The optical switch of claim 30 wherein the actuator for the latch arm is an electrostatic actuator.

34. A method of manufacturing multiple optical switch modules, each including an array of MEMS switches and an array of optical waveguides, comprising the steps of:  
providing a single-crystal silicon wafer substrate;  
selectively etching the wafer substrate with a crystallographic etching solution  
25 to define a plurality of cantilevered arms, control elements, and bases integrally coupled to one another; and  
bonding the silicon wafer in alignment to a wafer which includes optical waveguides.

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35. The method of claim 34 wherein said bonding step is anodic bonding.

36. The method of claim 34 wherein said bonding step is fusion bonding.

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AMENDED CLAIMS

[received by the International Bureau on 15 May 2001 (15.05.01);  
original claim 14 cancelled; original claims 1, 7-9, 12, 15, 21, 24, 27, 28 and 32 amended;  
remaining claims unchanged (5 pages)]

1. An optical switch comprising:  
a substrate including an optical waveguide, wherein the waveguide includes spaced-apart ports;  
an arm formed from a single-crystal silicon material and mounted in a cantilevered manner to the substrate;  
an actuator for deflecting said arm in a plane orthogonal to the plane of the substrate;  
and  
a control element mounted to said arm, whereby actuation of the arm moves the control element between the ports to control transmission of optical energy in the waveguide.
2. The optical switch of claim 1 wherein the substrate defines a planar optical circuit integrally including at least one waveguide.
3. The optical switch of claim 2 wherein the optical circuit includes a slot formed therein to define the ports of the waveguide.
4. The optical switch of claim 3 wherein the control element of the cantilevered arm selectively extends into the slot.
5. The optical switch of claim 4 wherein the control element is a mirror.
6. The optical switch of claim 1 wherein the actuator is a thermal actuator.
7. The optical switch of claim 6 wherein the thermal actuator includes a thin conductive film.
8. The optical switch of claim 1 wherein the actuator comprises a piezoelectric element coupled to the arm to deflect said arm.

AMENDED SHEET (ARTICLE 19)

9. An optical switch comprising:
- a substrate including an optical waveguide, wherein the waveguide includes spaced-apart ports;
  - an arm mounted in a cantilevered manner to the substrate;
  - an actuator for deflecting said arm in a plane orthogonal to the plane of the substrate;
  - a control element mounted to said arm, whereby actuation of the arm moves the control element between the ports to control transmission of optical energy in the waveguide; and
  - a latch arm mounted to the substrate and selectively coupled to the arm to hold the arm in an actuated position.
10. The optical switch of claim 9 wherein the latch arm includes an actuator for moving the latch arm in a direction orthogonal to the arm for overlying the arm when the arm and latch arm are actuated.
11. The optical switch of claim 10 wherein the actuator for the latch arm is a thermal actuator.
12. The optical switch of claim 10 wherein the actuator for the latch arm is a piezoelectric actuator.
13. The optical switch of claim 10 wherein the actuator for the latch arm is an electrostatic actuator.
15. An optical switch module comprising:
- an array of orthogonally extending optical waveguides formed in a planar substrate with a diagonal slots formed at the intersections of the waveguides to define input and output ports;
  - an array of MEMS switches formed in a single-crystal silicon wafer and mounted to the planar substrate, wherein each MEMS switch includes an arm mounted in a cantilevered fashion to the substrate for movement to selectively extend into a slot

to switch the optical energy in one waveguide of the substrate to another waveguide of the substrate; and  
electrical conductors deposited on a surface of said array of MEMS switches opposite said substrate.

16. A method of manufacturing an array of MEMS switches comprising the steps of:  
providing a single-crystal silicon wafer substrate;  
coating a surface of the substrate with a photolithographic film;  
exposing an etching pattern on the film with a photolithographic light source;  
reactive ion etching the film;  
applying a crystallographic etching solution to the exposed wafer substrate to define a plurality of arms, control elements, and bases integrally coupled to one another; and  
etching the silicon wafer adjacent each of the control elements to define cantilevered arms, each with the control element extending from one end thereof.
17. The method of claim 16 and further including depositing a reflective film on opposite sides of each of the control elements.
18. The method of claim 17 wherein said depositing step comprises depositing gold on the sides of the control element.
19. The method of claim 17 and further including applying an actuator on each of the cantilevered arms.
20. The method of claim 19 wherein the applying step comprises depositing an insulating strip on each of the arms and depositing a thermally conductive element over each of the insulating strips.
21. The method of claim 19 wherein the applying step comprises applying a piezoelectric material to each of the arms and a conductive material over the piezoelectric material.
22. The method of claim 16 and further including bonding the silicon wafer in alignment to an optical circuit array.

23. A latching optical switch comprising:  
a substrate including an optical waveguide, wherein the waveguide includes spaced-apart ports;  
a switching arm mounted in a cantilevered manner to the substrate and including an actuator for deflecting said arm in a plane orthogonal to the plane of the substrate, such that a control element mounted to said arm moves between the ports to control the transmission of optical energy in the waveguide; and  
a latch arm mounted to the substrate and including an actuator to selectively move the latch arm over the switching arm to hold the switching arm in an actuated position.
24. An optical switch module comprising:  
an array of orthogonally extending optical waveguides formed in a planar substrate with diagonal slots formed at the intersections of the waveguides to define input and output ports;  
an array of MEMS switches mounted to the planar substrate, wherein each MEMS switch includes an arm formed from a single-crystal silicon material and mounted in a cantilevered fashion to the substrate;  
an actuator for deflecting the arms in a plane orthogonal to the substrate; and  
a control element mounted to the arm, whereby the arm and control element are positioned on the substrate to selectively extend into a slot to switch the optical energy in one waveguide of the substrate to another waveguide of the substrate.
25. The optical switch of claim 24 wherein the control element is a mirror.
26. The optical switch of claim 24 wherein the actuator is a thermal actuator.
27. The optical switch of claim 26 wherein the thermal actuator includes a thin conductive film.
28. The optical switch of claim 24 wherein the actuator comprises a piezoelectric element coupled to the arm to deflect said arm.

AMENDED SHEET (ARTICLE 19)



29. An optical switch module comprising:
- an array of orthogonally extending optical waveguides formed in a planar substrate with diagonal slots formed at the intersections of the waveguides to define input and output ports;
  - an array of MEMS switches mounted to the planar substrate, wherein each MEMS switch includes an arm mounted in a cantilevered fashion to the substrate;
  - an actuator for deflecting the arms in a plane orthogonal to the substrate;
  - a control element mounted to the arm, whereby the arm and control element are positioned on the substrate to selectively extend into a slot to switch the optical energy in one waveguide of the substrate to another waveguide of the substrate; and
  - a latch arm mounted to the substrate and selectively coupled to the arm to hold the arm in an actuated position.
30. The optical switch of claim 29 wherein the latch arm includes an actuator for moving the latch arm in a direction orthogonal to the arm for overlying the arm when the arm and latch arm are actuated.
31. The optical switch of claim 30 wherein the actuator for the latch arm is a thermal actuator.
32. The optical switch of claim 30 wherein the actuator for the latch arm is a piezoelectric actuator.
33. The optical switch of claim 30 wherein the actuator for the latch arm is an electrostatic actuator.
34. A method of manufacturing multiple optical switch modules, each including an array of MEMS switches and an array of optical waveguides, comprising the steps of:
- providing a single-crystal silicon wafer substrate;
  - selectively etching the wafer substrate with a crystallographic etching solution to define a plurality of cantilevered arms, control elements, and bases integrally coupled to one another; and

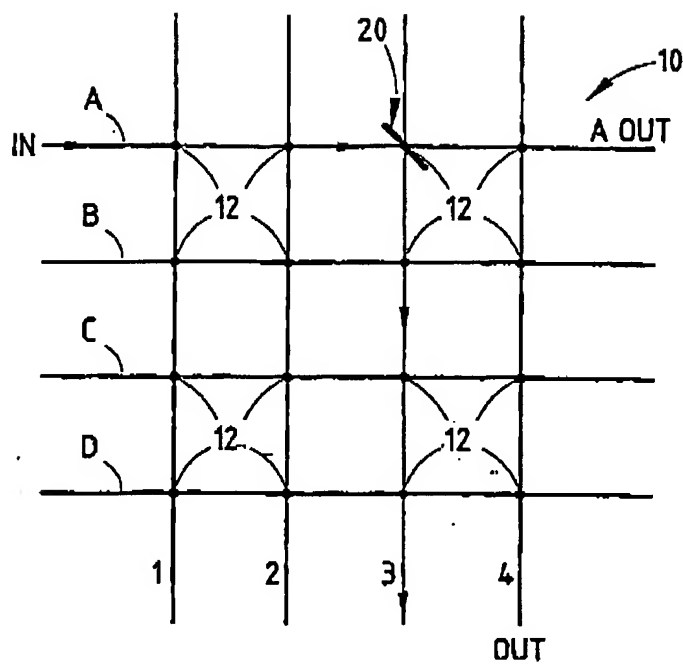


FIG. 1

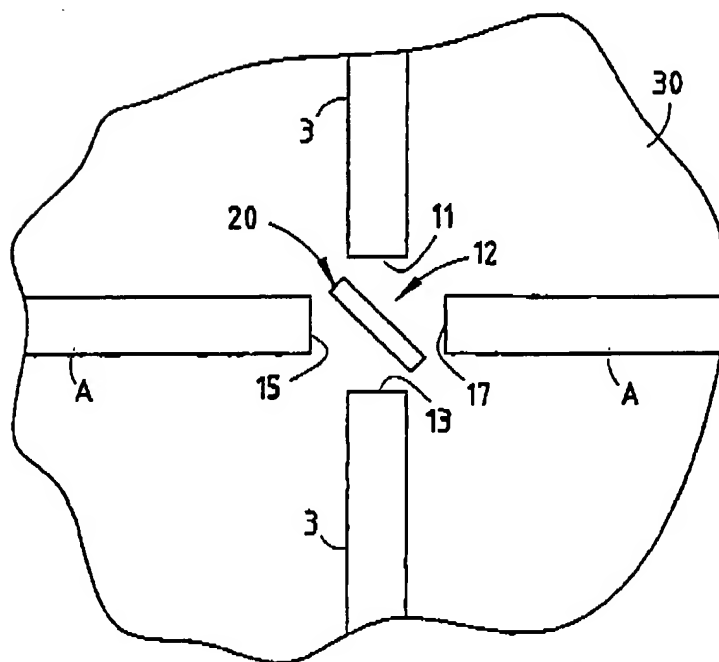
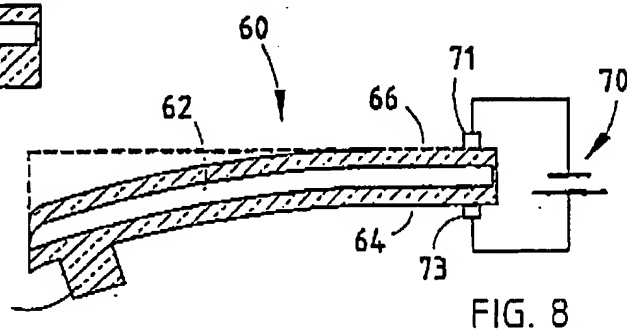
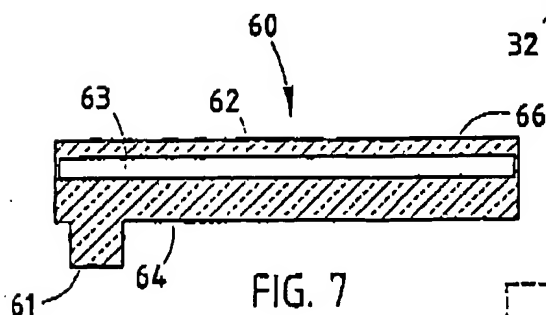
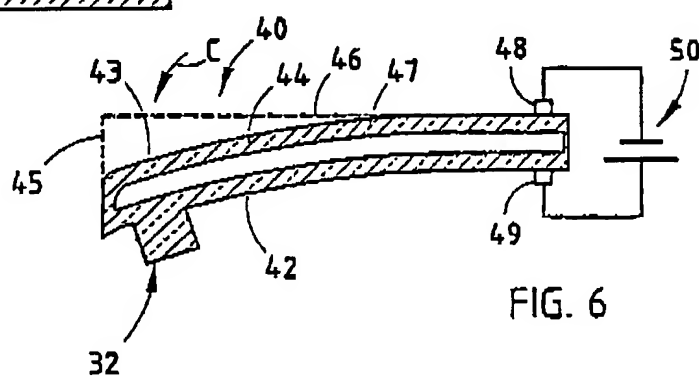
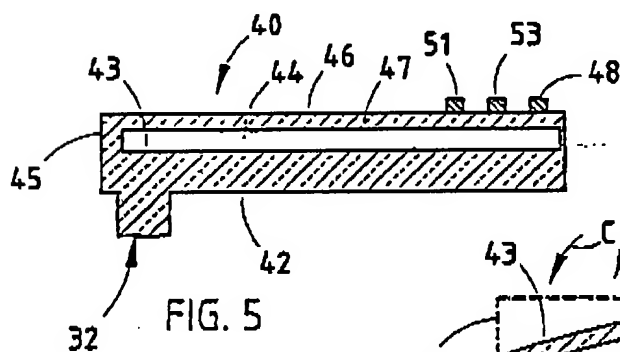
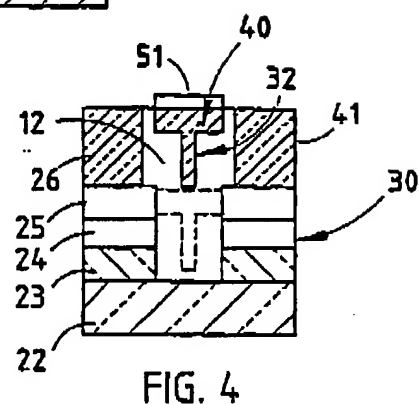
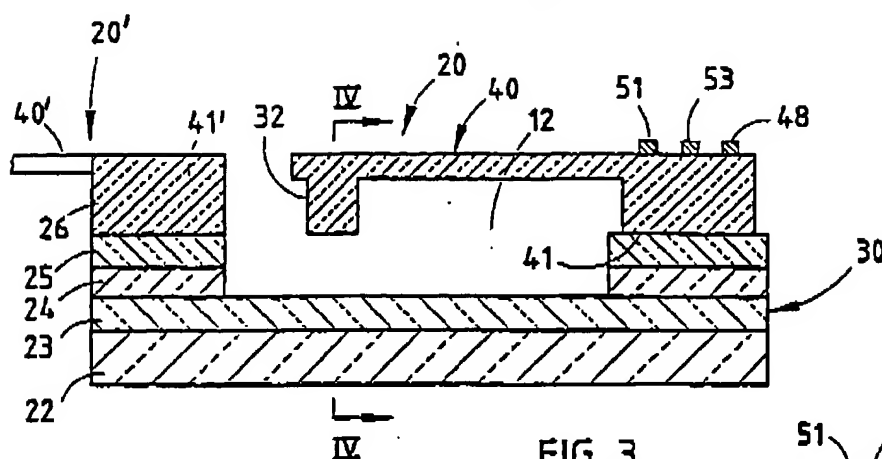


FIG. 2

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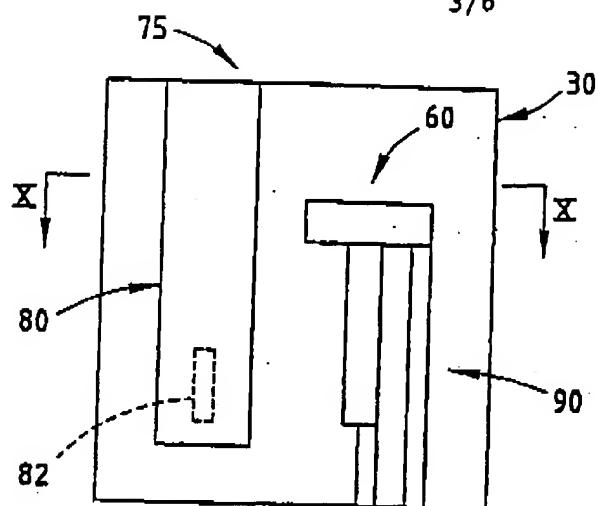


FIG. 9

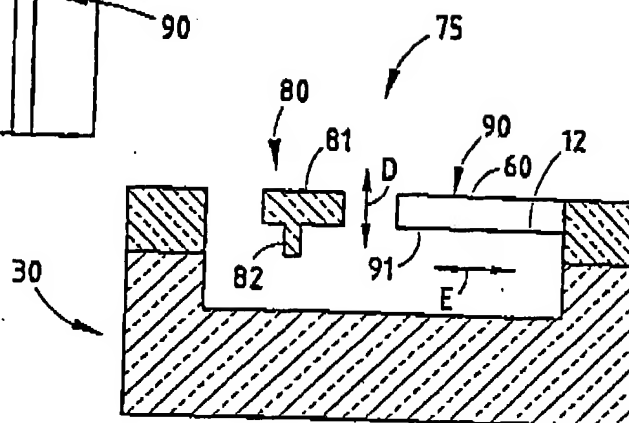


FIG. 10

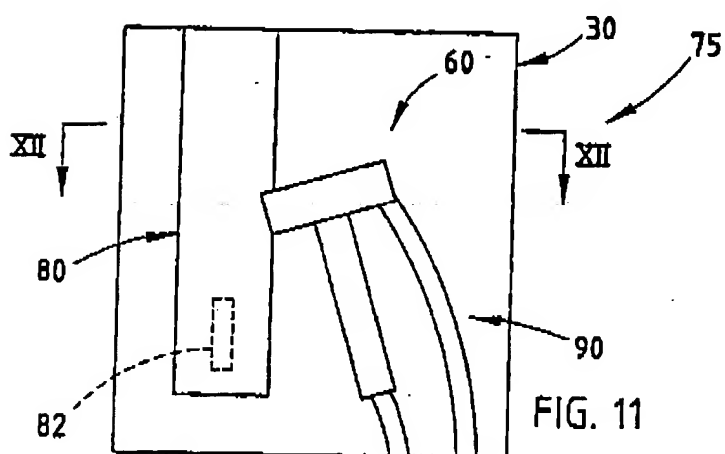


FIG. 11

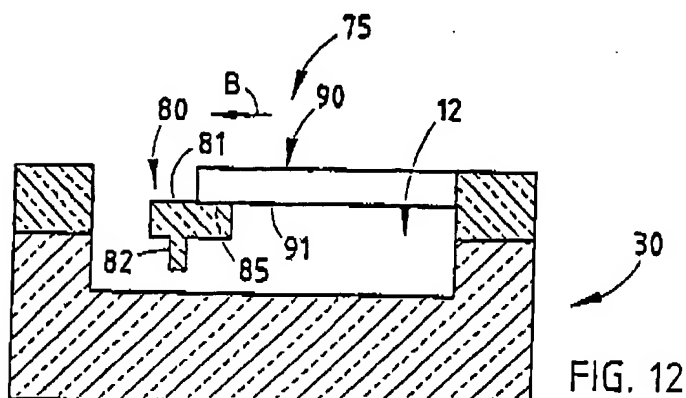


FIG. 12

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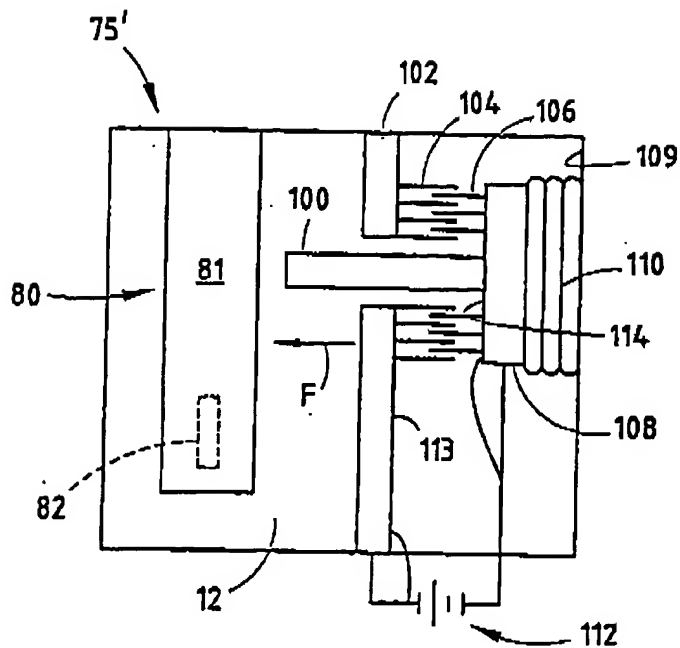


FIG. 13

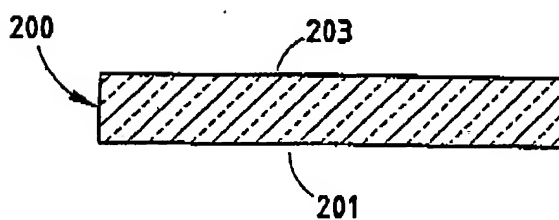


FIG. 14

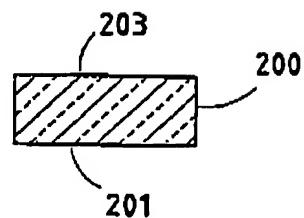


FIG. 15

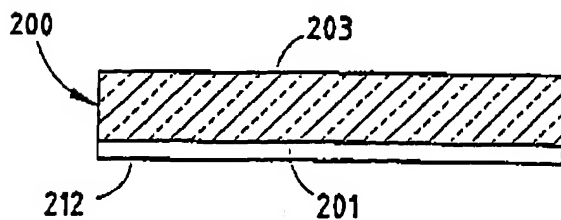


FIG. 16

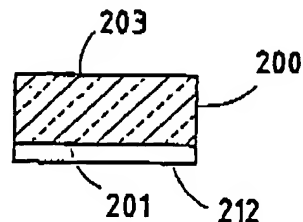


FIG. 17

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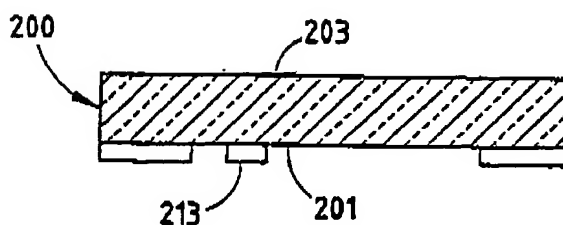


FIG. 18

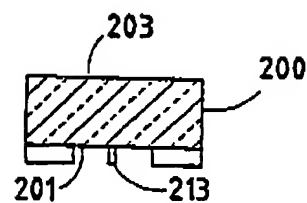


FIG. 19

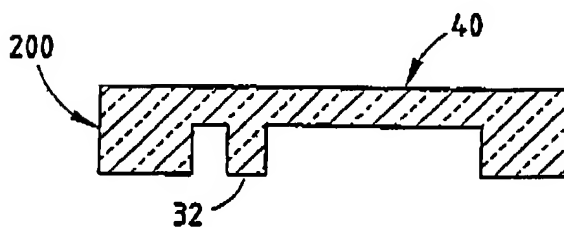


FIG. 20

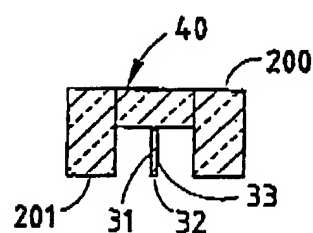


FIG. 21

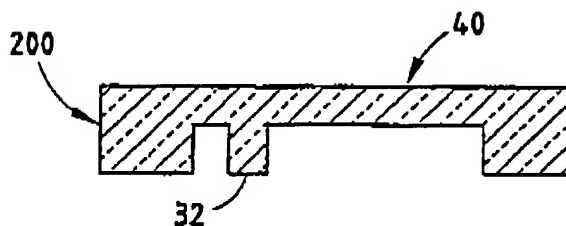


FIG. 22

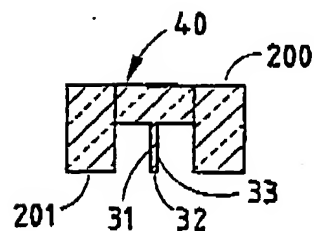


FIG. 23

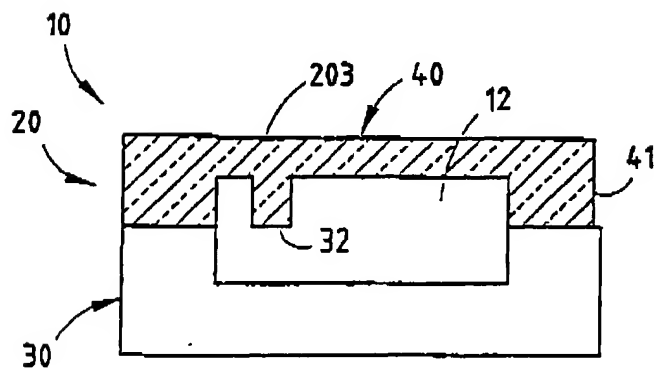


FIG. 24

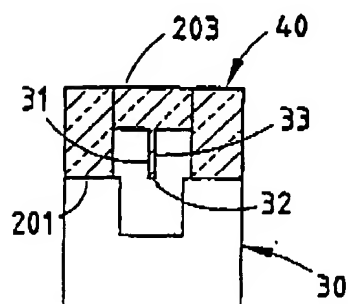


FIG. 25

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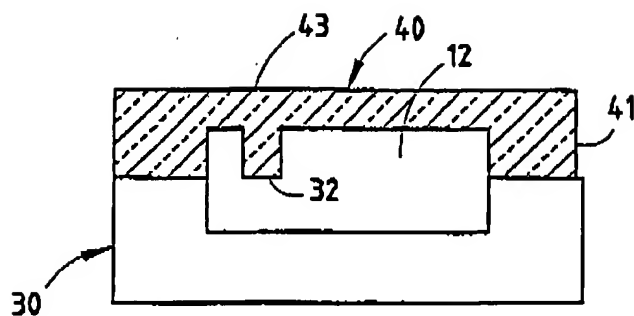


FIG. 26

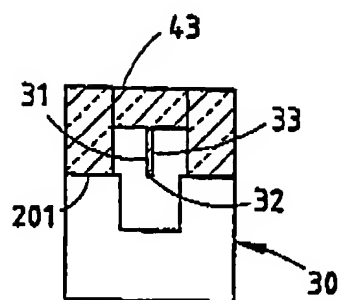


FIG. 27

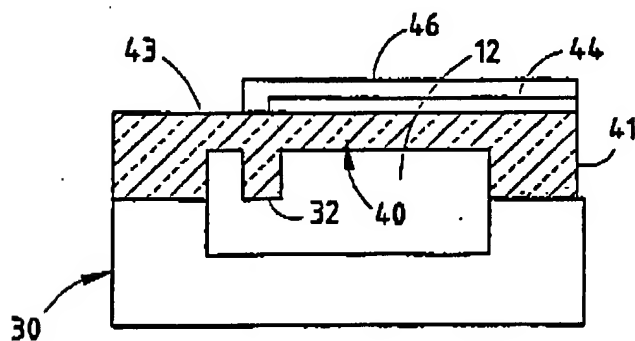


FIG. 28

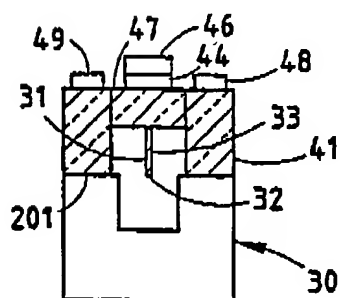


FIG. 29

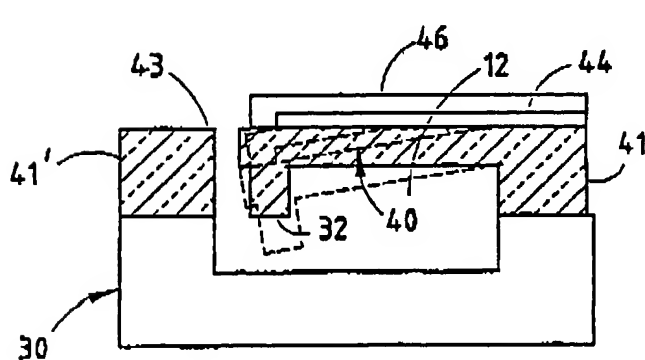


FIG. 30

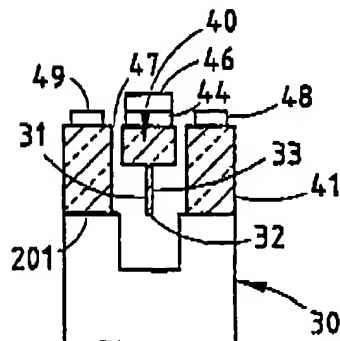


FIG. 31